# MA3X704 (MA704), MA3X704A (MA704A)

## Silicon epitaxial planar type

For switching

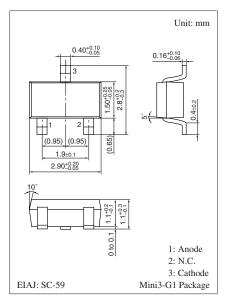
For wave detection

#### ■ Features

- $\bullet$  Low forward voltage  $V_F$  and good wave detection efficiency  $\eta$
- Small temperature coefficient of forward characteristic
- Small reverse current I<sub>R</sub>

## ■ Absolute Maximum Ratings $T_a = 25$ °C

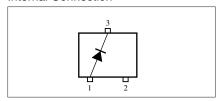
Parameter		Symbol	Rating	Unit	
Reverse voltage	MA3X704	$V_R$	15	V	
	MA3X704A		30		
Maximum peak	MA3X704	$V_{RM}$	15	V	
reverse voltage	MA3X704A		30		
Peak forward current		$I_{FM}$	150	mA	
Forward current		$I_F$	30	mA	
Junction temperature		T <sub>j</sub>	125	°C	
Storage temperature		$T_{stg}$	-55 to +125	°C	



## Marking Symbol

Note) The part numbers in the parenthesis show conventional part number.

• MA3X704: M1K • MA3X704A: M1L Internal Connection

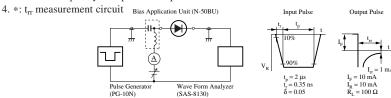


## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage		$V_{F1}$	$I_F = 1 \text{ mA}$			0.4	V
		V <sub>F2</sub>	$I_F = 30 \text{ mA}$			1.0	
Reverse current	MA3X704	$I_R$	$V_R = 15 \text{ V}$			200	nA
	MA3X704A		$V_R = 30 \text{ V}$			300	
Terminal capacitance		C <sub>t</sub>	$V_R = 1 \text{ V, f} = 1 \text{ MHz}$		1.5		pF
Reverse recovery time * t		t <sub>rr</sub>	$I_F = I_R = 10 \text{ mA}$		1.0		ns
			$I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$				
Detection efficiency		η	$V_{IN} = 3 V_{(peak)}$ , $f = 30 MHz$		65		%
			$R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$				

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 2 GHz.

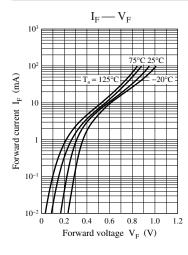
 $R_{\circ} = 50 \Omega$ 

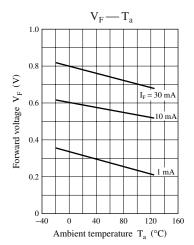


 $R_i = 50 \Omega$ 

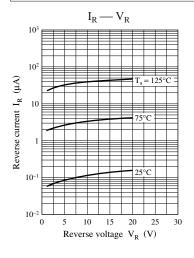
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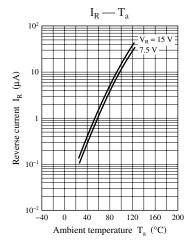
### Common characteristics charts

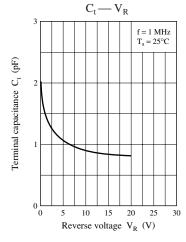




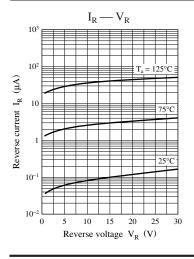
## Characteristics charts of MA3X704

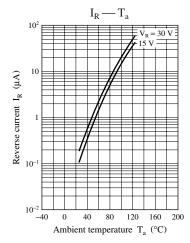


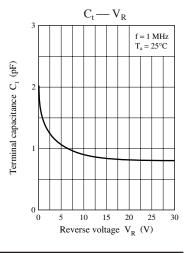




### Characteristics charts of MA3X704A







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